Power MOSFET 40 V, 75 A, 9.3 mΩ, Single N–Channel

Features

- Low R_{DS(on)}
- Low Capacitance
- Optimized Gate Charge
- NVMFS5834NLWF Wettable Flanks Product
- NVMFS Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25° C unless otherwise stated)

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Parameter			Symbol	Value	Unit	
Drain-to-Source Voltage			V _{DSS}	40	V	
Gate-to-Source Voltage			V _{GS}	±20	V	
Continuous Drain		$T_A = 25^{\circ}C$	I _D	14	А	
Current R _{θJA} (Note 1)	Steady	T _A = 100°C	1	12		
Power Dissipation		T _A = 25°C	PD	3.6	W	
R _{θJA} (Note 1)		T _A = 100°C	1	2.5		
Continuous Drain	State	$T_{C} = 25^{\circ}C$	۱ _D	75	А	
Current R _{θJC} (Note 1)		T _C = 100°C		63		
Power Dissipation		$T_{C} = 25^{\circ}C$	PD	107	W	
$R_{\theta JC}$ (Note 1)		$T_{C} = 100^{\circ}C$	1	75		
Pulsed Drain Current	t _p = 10 μs		I _{DM}	276	A	
Operating Junction and Storage Temperature			T _J , T _{STG}	–55 to +175	°C	
Source Current (Body Diode)			۱ _S	75	А	
Single Pulse Drain-to-Source Avalanche Energy (L = 0.1 mH)			EAS	48	mJ	
			IAS	31	А	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case (Bottom) (Note 1)	$R_{ ext{ heta}JC}$	1.4	
Junction-to-Case (Top) (Note 1)	$R_{\theta JC}$	4.5	
Junction-to-Ambient Steady State (Note 1)	R_{\thetaJA}	41	°C/W
Junction-to-Ambient Steady State (Note 2)	R_{\thetaJA}	75	

1. Surface-mounted on FR4 board using 1 sq-in pad

(Cu area = 1.127 in sq [2 oz] including traces).

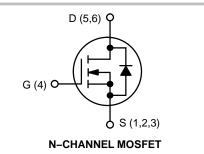
2. Surface-mounted on FR4 board using 0.155 in sq (100mm²) pad size.

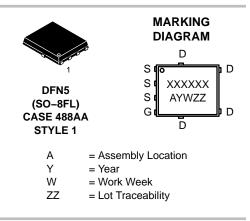


ON Semiconductor®

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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
40 V	9.3 mΩ @ 10 V	75 A
40 V	13.6 mΩ @ 4.5 V	75 4





ORDERING INFORMATION

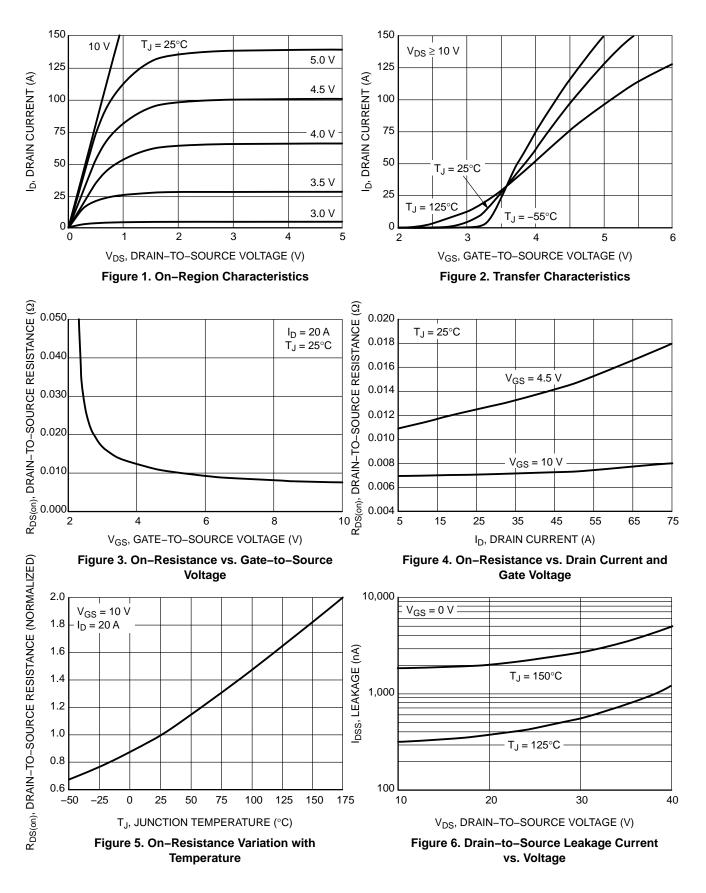
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

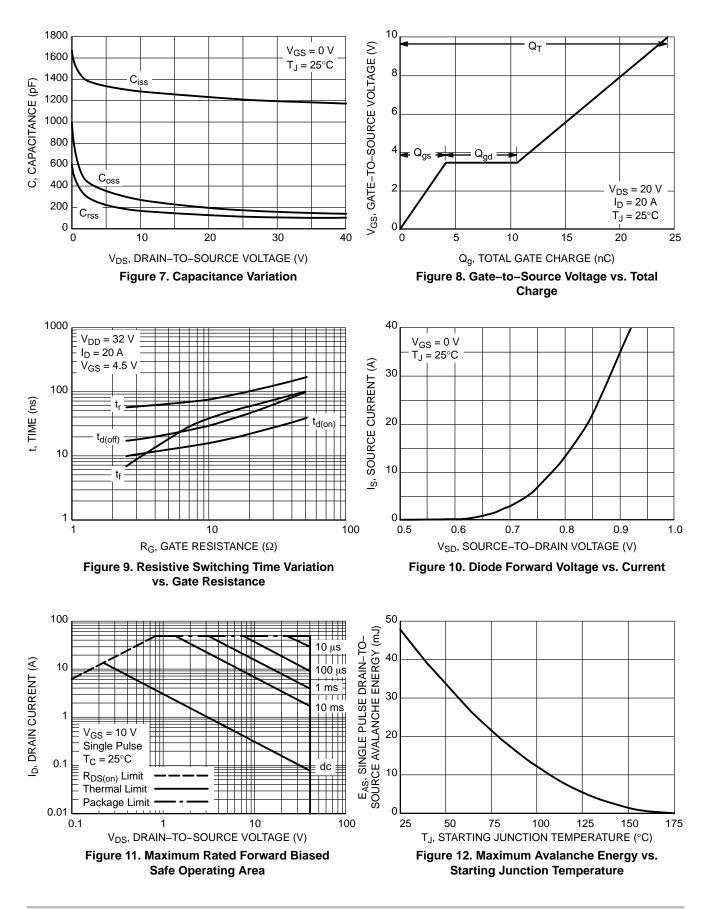
Parameter	Symbol	Test Condition		Min	Тур	Мах	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 V, I_D = 250 \mu A$		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J				34.7		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	T _J = 25 °C			1.0	
		$V_{DS} = 40 \text{ V}$ $T_{J} = 125^{\circ}\text{C}$				100	μΑ
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$				±100	nA
ON CHARACTERISTICS (Note 3)							-
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D$	= 250 μA	1.0		3.0	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				5.7		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 20 A		7.1	9.3	mΩ
		$V_{GS} = 4.5 V$	I _D = 20 A		11.3	13.6	
Forward Transconductance	9fs	$V_{DS} = 5 V, I_{D}$	= 20 A		29		S
CHARGES, CAPACITANCES & GATE RESIS	STANCE						
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 20 V			1231		pF
Output Capacitance	C _{OSS}				198		
Reverse Transfer Capacitance	C _{RSS}				141		
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 10 V, V _{DS} = 20 V; I _D = 20 A			24		
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 4.5 V, V _{DS} = 20 V; I _D = 20 A			12		nC
Threshold Gate Charge	Q _{G(TH)}				1.0		
Gate-to-Source Charge	Q _{GS}				4.2		
Gate-to-Drain Charge	Q _{GD}				6.3		
Plateau Voltage	V _{GP}				3.4		V
Gate Resistance	R _G				0.7		Ω
SWITCHING CHARACTERISTICS (Note 4)	1						
Turn-On Delay Time	t _{d(ON)}				10		
Rise Time	t _r	V_{GS} = 4.5 V, V_{DS} = 20 V, I _D = 20 A, R _G = 2.5 Ω			56.4		- ns
Turn-Off Delay Time	t _{d(OFF)}				17.4		
Fall Time	t _f				6.6		
DRAIN-SOURCE DIODE CHARACTERISTIC	s						
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V,$ $I_{S} = 20 A$	T _J = 25°C		0.84	1.2	
			T _J = 125°C		0.72		V
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dIS/dt = 100 A/μs, I _S = 20 A			18		
Charge Time	ta				10		ns
Discharge Time	t _b				8.0		
Reverse Recovery Charge	Q _{RR}				11		nC

Fulse rest, pulse width ≤ 300 µs, duly cycle ≤ 2 %.
Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

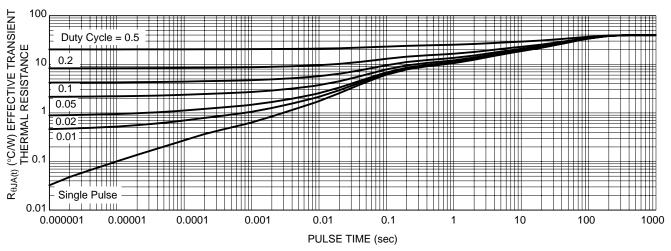


Figure 13. Thermal Response

Device	Marking	Package	Shipping [†]
NTMFS5834NLT1G	5834L	DFN5 (Pb–Free)	1500 / Tape & Reel
NVMFS5834NLT1G	V5834L	DFN5 (Pb–Free)	1500 / Tape & Reel
NVMFS5834NLWFT1G	5834LW	DFN5 (Pb–Free)	1500 / Tape & Reel
NVMFS5834NLT3G	V5834L	DFN5 (Pb–Free)	5000 / Tape & Reel
NVMFS5834NLWFT3G	5834LW	DFN5 (Pb–Free)	5000 / Tape & Reel

DEVICE ORDERING INFORMATION

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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